2SD2053

Silicon NPN triple diffusion planar type

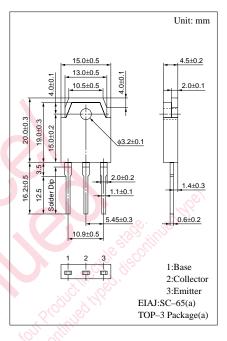
For high power amplification Complementary to 2SB1362

Features

- High breakdown voltage: $V_{CEO} = 150V$
- Satisfactory linearity of foward current transfer ratio h_{FE}
- Wide area of safe operation (ASO)
- High transition frequency f_T

Absolute Maximum Ratings $(1_c=25 \text{ C})$							
Parameter		Symbol	Ratings	Unit			
Collector to base voltage		V _{CBO}	150	V			
Collector to emitter voltage		V _{CEO}	150	V			
Emitter to base voltage		V _{EBO}	5	V			
Peak collector current		I _{CP}	15	A			
Collector current		I _C	9	А			
Collector power	$T_C=25^{\circ}C$	D	100				
dissipation	Ta=25°C	P _C	2.5	W			
Junction temperature		Tj	150	°C			
Storage temperature		T _{stg}	-55 to +150	°C			

Absolute Maximum Ratings (T_C=25°C)

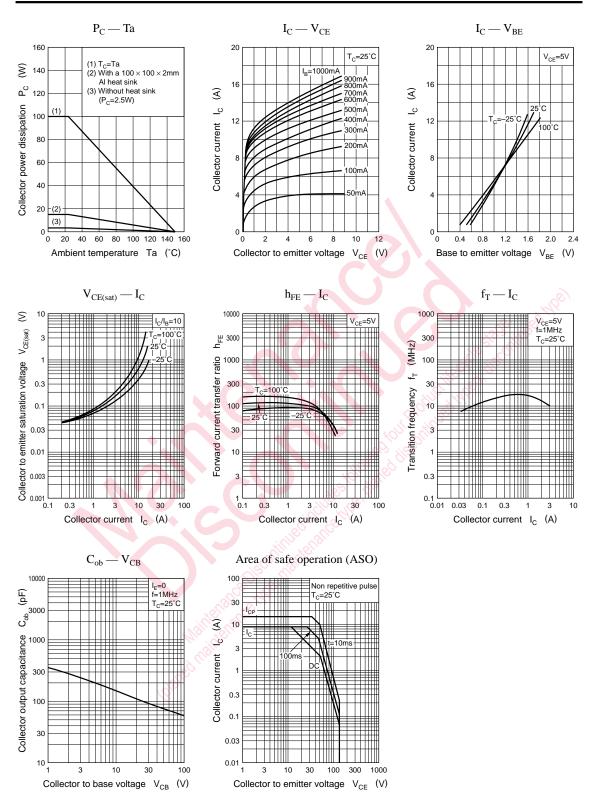


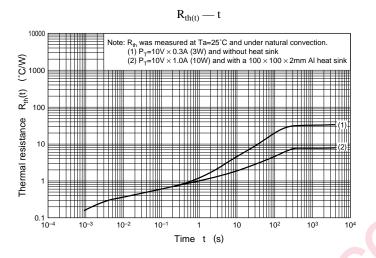
Electrical Characteristics (T_c=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I _{CBO}	$V_{CB} = 150V, I_E = 0$			50	μA
Emitter cutoff current	I _{EBO}	$V_{EB} = 3V, I_{C} = 0$			50	μA
	h _{FE1}	$V_{CE} = 5V, I_{C} = 20mA$	20			
Forward current transfer ratio	h _{FE2} *	$V_{CE} = 5V, I_C = 1A$	60		200	
	h _{FE3}	$V_{CE} = 5V, I_C = 7A$	20			
Base to emitter voltage	V _{BE}	$V_{CE} = 5V, I_C = 7A$			1.8	v
Collector to emitter saturation voltage	V _{CE(sat)}	$I_{C} = 7A, I_{B} = 0.7A$			2.0	v
Transition frequency		$V_{CE} = 5V, I_C = 0.5A, f = 1MHz$		20		MHz
Collector output capacitance	C _{ob}	$V_{CB}=10V,I_{E}=0,f=1MHz$		150		pF

*hFE2 Rank classification

Rank	Q	S	Р
h _{FE2}	60 to 120	80 to 160	100 to 200





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